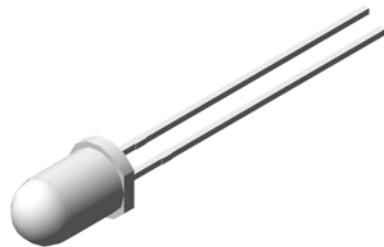


5mm Round 850nm Infrared LED

UT 5428

Description

The UT 5428 used high efficiency 850nm GaAlAs materials molded into water clear lens. Comparing conventional GaAs/GaAs technology under similar wavelength, GaAlAs offers much higher radiant power. The viewing angles being offered is 15 degree. The most suitable application is Infrared radiation source for CMOS cameras.



Applications

- Infrared radiation source for CMOS cameras
- Free air transmission system
- Infrared applied system



pb-free

Electronic Optical Characteristics (at 20mA):

Part Number	λ (nm)		Lens Color	mW/sr		View Angle	VF(V)	
	λ p	$\Delta \lambda$		Min.	Typ.		Typ.	Max.
UT 5428	850	45	Water Clear	7.5	17	15	1.4	1.7

* Radiant Intensity Typ. 140 mW/sr @ IF=100mA, Pulse Width \leq 100 μ sec, Duty \leq 1%, VF @ 2.40 Max.

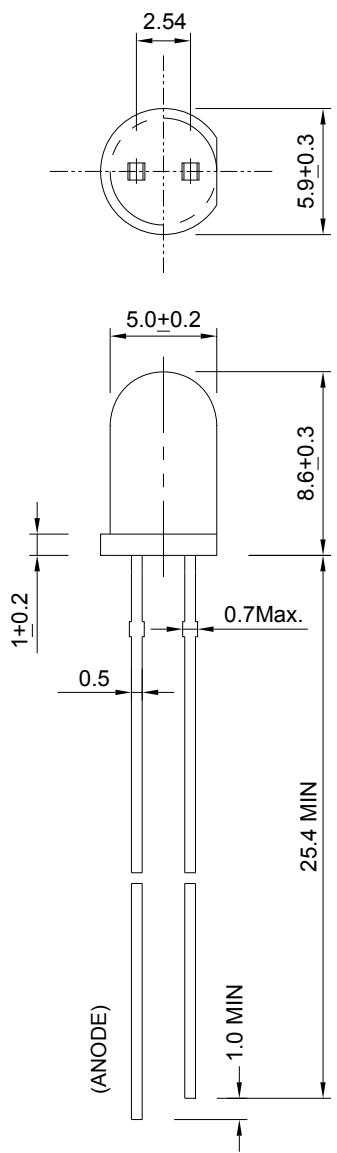
Absolute Maximum Ratings (at Ta=25°C)

Parameter	Symbol	Rating	Unit	Condition
Continuous Forward Current	I _F	100	mA	
Peak Forward Current	I _P	1.0	A	Pulse width=100us Duty Cycle = 1%
Soldering Temperature	T _{sol}	260	°C	4mm from lens body less than 5 seconds
Storage Temperature	T _{stg}	-40 - +85	°C	
Operating Temperature	T _{opr}	-25 - +85	°C	
Power Dissipation	P _D	150	mW	25°C Free Air Temperature

Note: Please take note the Absolute Maximum Rating values. Any operation beyond the specified ratings in this table will result degradation of LED life-span and may cause LED to fail.

Package Dimension:

unit: mm

**Notes:**

1. All dimensions are millimeters.
2. Tolerance is ± 0.2 mm unless otherwise specified.
3. Specifications are subject to change without notice.

Optical Characteristics Curves

